





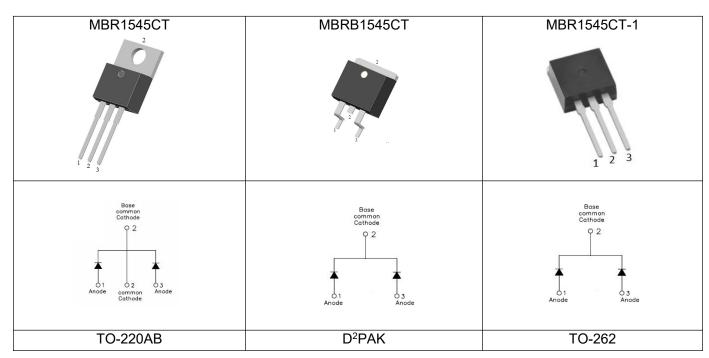
# MBR1545CT/MBRB1545CT/MBR1545CT-1 SCHOTTKY RECTIFIER

#### **Features**

- 150 °C T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- · Terminals finish: Tin Lead-free plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Applications**

- · Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection



#### Maximum Ratings@Tc=25°C unless otherwise specified

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	45	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=125°C, rectangular wave form	7.5(Per Leg) 15(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse	180	А

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#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop	V <sub>F1</sub>	@ 15A, Pulse, T <sub>J</sub> = 25 °C	0.70	0.84	V
(Per Leg)*	$V_{F2}$	@ 15A, Pulse, T <sub>J</sub> = 125 °C	0.67	0.72	V
Reverse Current (Per Leg)*	I <sub>R1</sub>	$@V_R = \text{rated } V_R$ $T_J = 25  ^{\circ}\text{C}$	0.02	1.0	mA
	I <sub>R2</sub>	$@V_R = \text{rated } V_R$ $T_J = 125 ^{\circ}\text{C}$	12	15	mA
Junction Capacitance(Per Leg)	Ст	$@V_R = 5V, T_C = 25  ^{\circ}C$ $f_{SIG} = 1MHz$	305	400	pF
Typical Series Inductance (Per Leg)	Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

 $<sup>^*</sup>$  Pulse width < 300  $\mu$ s, duty cycle < 2%

#### **Thermal-Mechanical Specifications:**

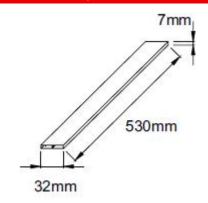
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case(Per Leg)	R <sub>θJC</sub>	DC operation	3.0	°C/W
Typical Thermal Resistance, Junction to Case(Per package)	$R_{ heta JA}$	DC operation	60	°C/W
Typical Thermal Resistance, Case to Heat Sink	R <sub>0</sub> CS	Mounting surface, smooth and greased	0.50	°C/W
Case Style	TO-220AB D <sup>2</sup> PAK TO-262			

## **Tube Specification**

Device	Package	Weight	Shipping
MBR1545CT	TO-220AB	1.8g	50pcs / tube
MBRB1545CT	D <sup>2</sup> PAK	1.85g	800pcs / reel
MBR1545CT-1	TO-262	1.85g	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

## **Tube Specification(TO-220AB/TO-262)**



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## **Ratings and Characteristics Curves**

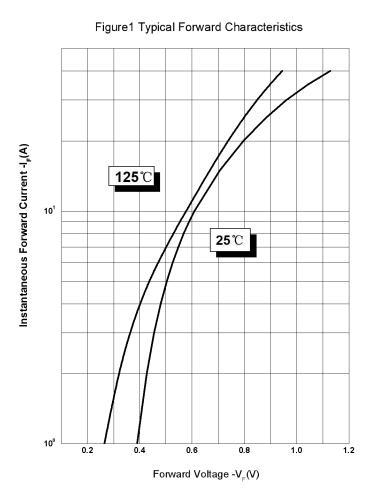


Figure 2 Typical Reverse Characteristics

102
101
101
102
103
9 18 27 36 45

Reverse Voltage -V<sub>B</sub>(V)

Figure 3 Typical Junction Capacitance

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#### **Marking Diagram**



Where XXXXX is YYWWL

MBR = Device Type
B = Package type
15 = Forward Current (15A)
45 = Reverse Voltage (45V)
CT -1 = Configuration
SSG = SSG

 SSG
 = SSG

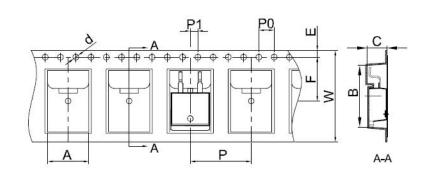
 YY
 = Year

 WW
 = Week

 L
 = Lot Number

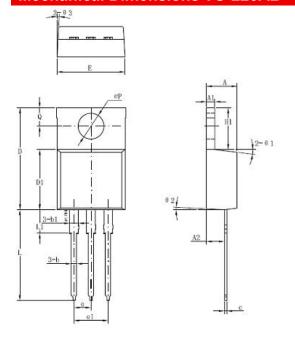
**Cautions:** Molding resin Epoxy resin UL:94V-0

# **Carrier Tape Specification D2PAK**



Symbol	Millimeters		
Symbol	Min.	Max.	
Α	10.70	10.90	
В	16.03	16.23	
С	5.11	5.31	
d	1.45	1.65	
E	1.65	1.85	
F	11.40	11.60	
P0	3.90	4.10	
Р	15.90	16.10	
P1	1.90	2.10	
W	23.90	24.30	

## **Mechanical Dimensions TO-220AB**



Symbol	Dimensions in millimeters			
	Min	Typical	Max	
А	3.56	-	4.83	
A1	0.51	-	1.4	
A2	2.03	-	2.92	
b	0.38	-	1.02	
b1	1.14	-	1.78	
С	0.31	-	0.61	
D	14.22	-	16.51	
D1	8.38	-	9.42	
E	9.65	-	10.67	
е	-	2.54	-	
e1	-	5.08	-	
H1	5.84	-	6.86	
L	12.7	-	14.73	
L1	-	-	6.35	
ФР	-	3.56	-	
Q	2.54	-	3.43	

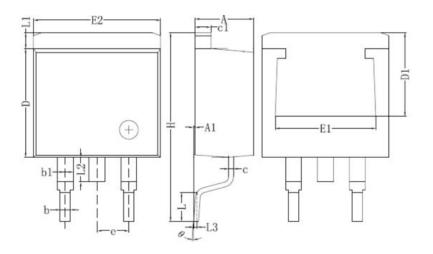
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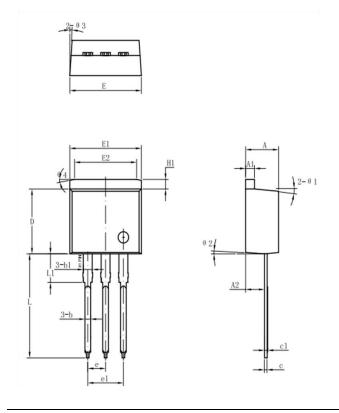


## **Mechanical Dimensions D<sup>2</sup>PAK**



Complete al	Dimensions in millimeters		
Symbol	Min.	Max.	
Α	4.06	4.83	
A1	0	0.26	
b	0.51	0.99	
b1	1.14	1.78	
С	0.31	0.74	
c1	1.14	1.65	
D	8.38	9.65	
D1	6.4		
E1	6.22		
E2	9.65	10.67	
е	2.541	BSC	
Н	14.6	15.88	
L	1.78	2.8	
L1	-	1.68	
L2	-	2.2	
L3	0.255BSC		
Θ	0	8°	

# **Mechanical Dimensions TO-262**



Symbol	Millimeters			
	Min.	Typical	Max.	
Α	4.55	4.70	4.85	
A1	1.17	1.27	1.37	
A2	2.59	2.69	2.89	
В	1.22	1.37	1.47	
b	0.71	0.81	0.96	
b1		1.27		
С	0.36	0.38	0.61	
D	8.55	8.70	8.85	
E	10.01	10.16	10.31	
E1	9.88	10.08	10.28	
е		2.54		
e1		5.08		
H1	1.17	1.27	1.37	
L	13.00	13.86	14.08	
L1		3.8		
Θ1		5°		
Θ2		4°		
Θ3		4°		
Θ4		10°		

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## MBR1545CT MBRB1545CT MBR1545CT-1

#### Technical Data Data Sheet N0736, Rev. A





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